

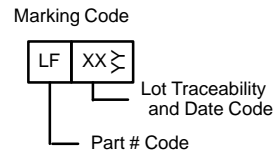
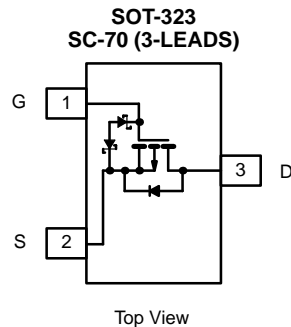


P-Channel 1.8-V (G-S) MOSFET

PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ (Ω)	I_D (A)
-12	0.290 @ $V_{GS} = -4.5$ V	± 0.91
	0.435 @ $V_{GS} = -2.5$ V	± 0.74
	0.580 @ $V_{GS} = -1.8$ V	± 0.64



ESD Protected
3000 V



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)				
Parameter	Symbol	5 secs	Steady State	Unit
Drain-Source Voltage	V_{DS}	-12		V
Gate-Source Voltage	V_{GS}	± 8		
Continuous Drain Current ($T_J = 150^\circ\text{C}$) ^a	I_D	$T_A = 25^\circ\text{C}$	± 0.91	A
		$T_A = 70^\circ\text{C}$	± 0.72	
Pulsed Drain Current	I_{DM}	± 3		A
Continuous Diode Current (Diode Conduction) ^a	I_S	-0.28	-0.24	
Maximum Power Dissipation ^a	P_D	$T_A = 25^\circ\text{C}$	0.34	W
		$T_A = 70^\circ\text{C}$	0.22	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 to 150		$^\circ\text{C}$

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^a	R_{thJA}	$t \leq 5$ sec	315	$^\circ\text{C/W}$
		Steady State	360	
Maximum Junction-to-Foot (Drain)	R_{thJF}	285	340	

Notes

a. Surface Mounted on 1" x 1" FR4 Board.



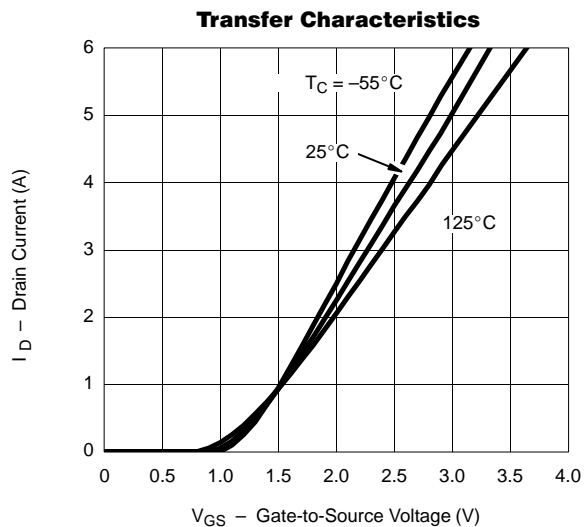
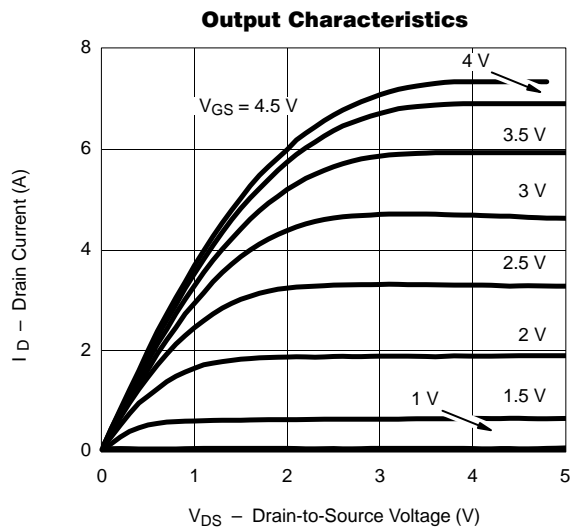
SPECIFICATIONS (T_J = 25 °C UNLESS OTHERWISE NOTED)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250 μA	-045			V
Gate-Body Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ±4.5 V			±1	μA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -9.6 V, V _{GS} = 0 V			-1	μA
		V _{DS} = -9.6 V, V _{GS} = 0 V, T _J = 70 °C			-5	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = -5 V, V _{GS} = -4.5 V	-3			A
Drain-Source On-State Resistance ^a	r _{DS(on)}	V _{GS} = -4.5 V, I _D = -1 A		0.240	0.290	Ω
		V _{GS} = -2.5 V, I _D = -0.5 A		0.350	0.435	
		V _{GS} = -1.8 V, I _D = -0.3 A		0.480	0.580	
Forward Transconductance ^a	g _{fs}	V _{DS} = -5 V, I _D = -1 A		3.5		S
Diode Forward Voltage ^a	V _{SD}	I _S = -1 A, V _{GS} = 0 V			-1.2	V
Dynamic^b						
Total Gate Charge	Q _g	V _{DS} = -6 V, V _{GS} = -4.5 V, I _D = -1 A		3.2	5	nC
Gate-Source Charge	Q _{gs}			0.69		
Gate-Drain Charge	Q _{gd}			0.61		
Turn-On Delay Time	t _{d(on)}	V _{DD} = -6 V, R _L = 6 Ω I _D ≅ -1 A, V _{GEN} = -4.5 V, R _G = 6 Ω		210	340	ns
Rise Time	t _r			450	720	
Turn-Off Delay Time	t _{d(off)}			910	1550	
Fall Time	t _f			1000	1600	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = -1 A, di/dt = 100 A/μs		540	860	

Notes

- a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.
- b. Guaranteed by design, not subject to production testing.

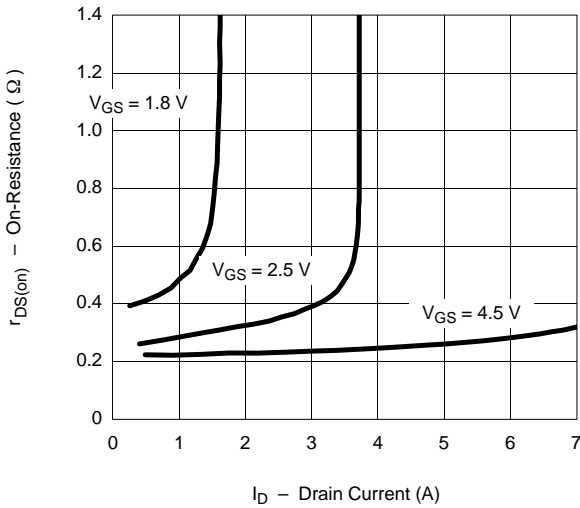
TYPICAL CHARACTERISTICS (25 °C UNLESS NOTED)



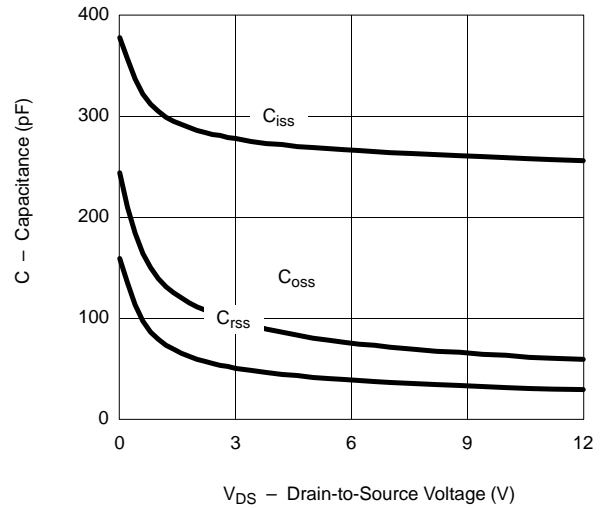


TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

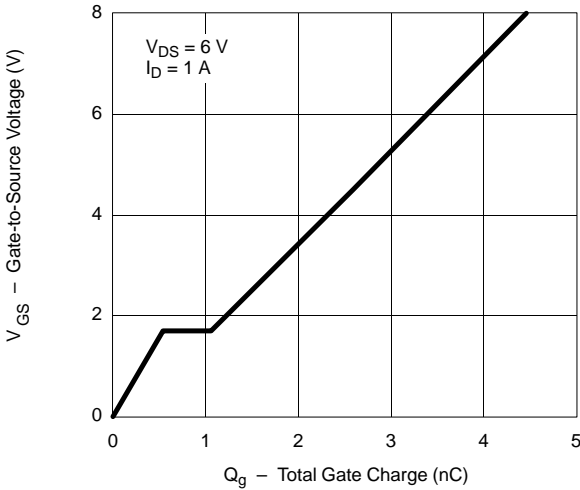
On-Resistance vs. Drain Current



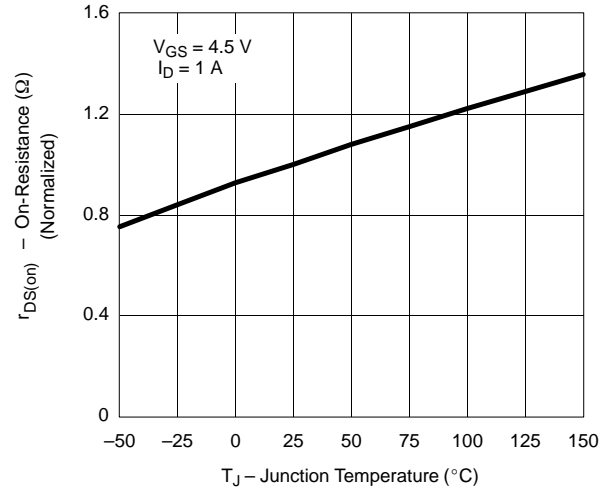
Capacitance



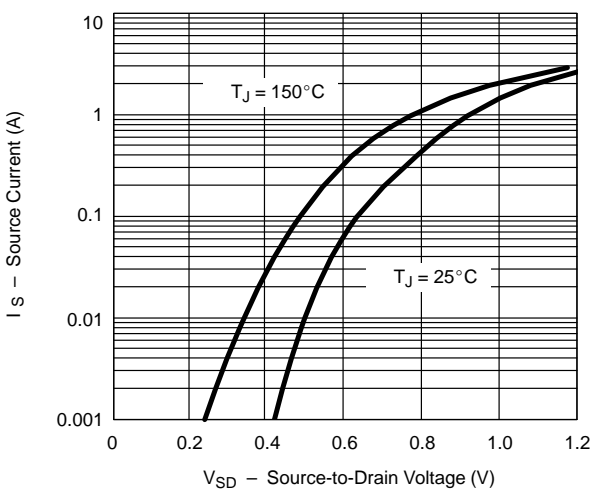
Gate Charge



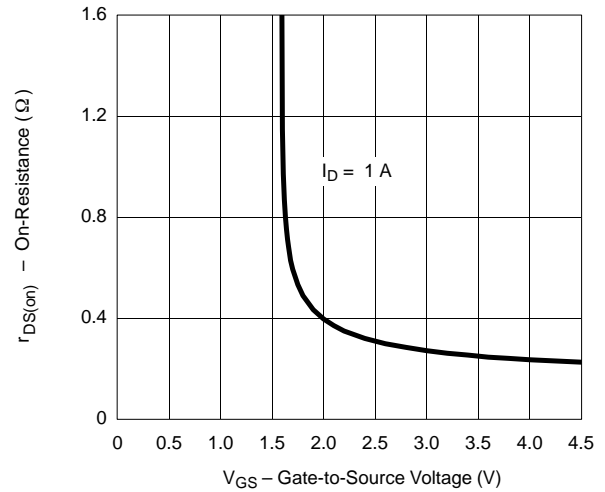
On-Resistance vs. Junction Temperature



Source-Drain Diode Forward Voltage



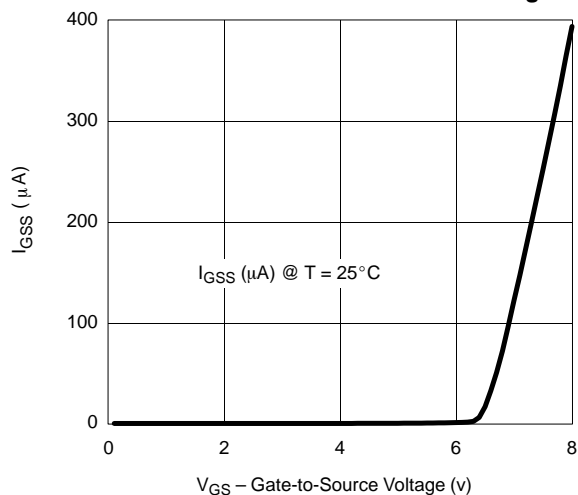
On-Resistance vs. Gate-to-Source Voltage



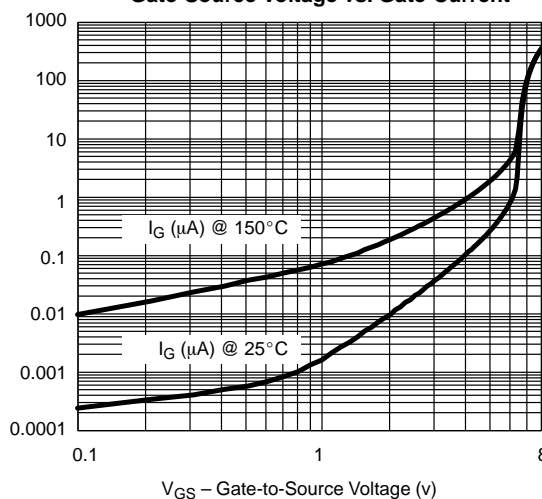


TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

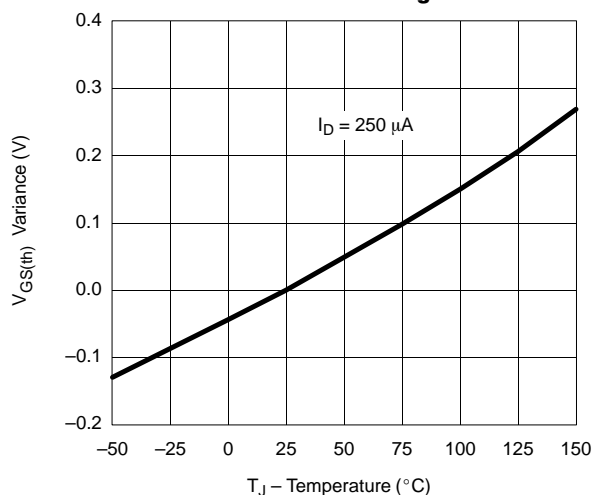
Gate-Current vs. Gate-Source Voltage



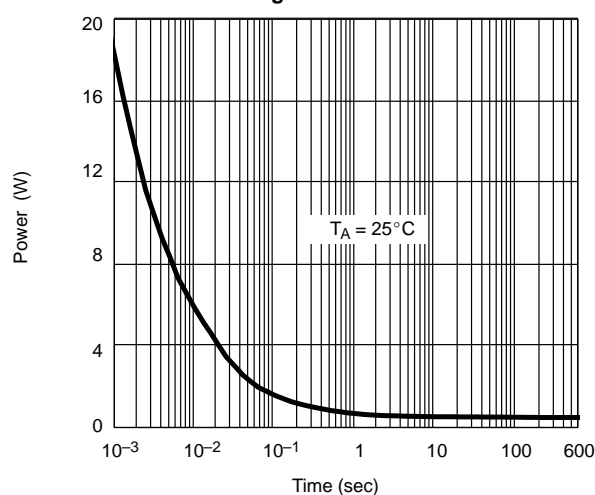
Gate-Source Voltage vs. Gate-Current



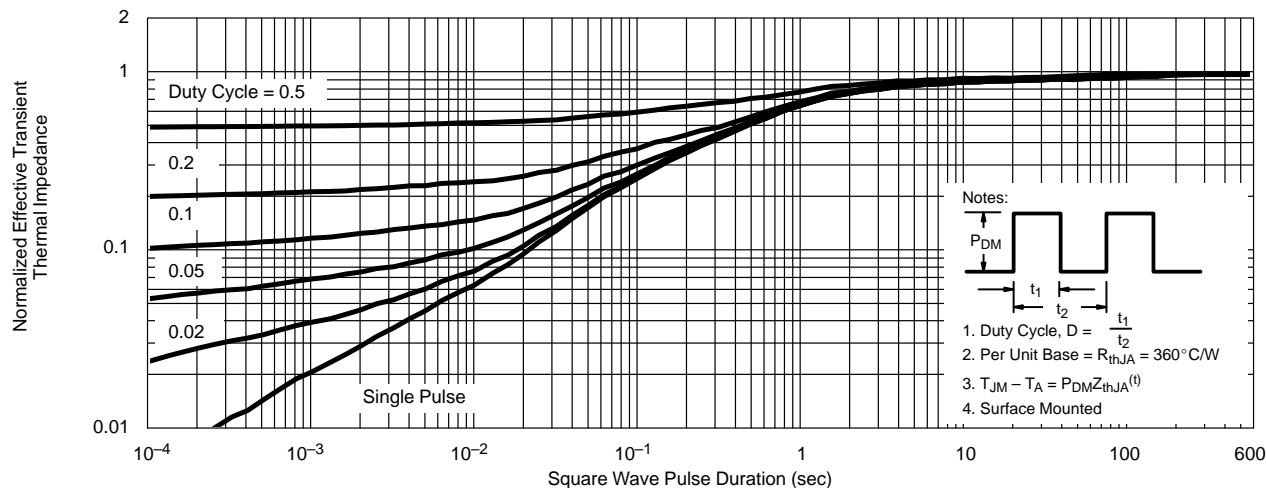
Threshold Voltage



Single Pulse Power

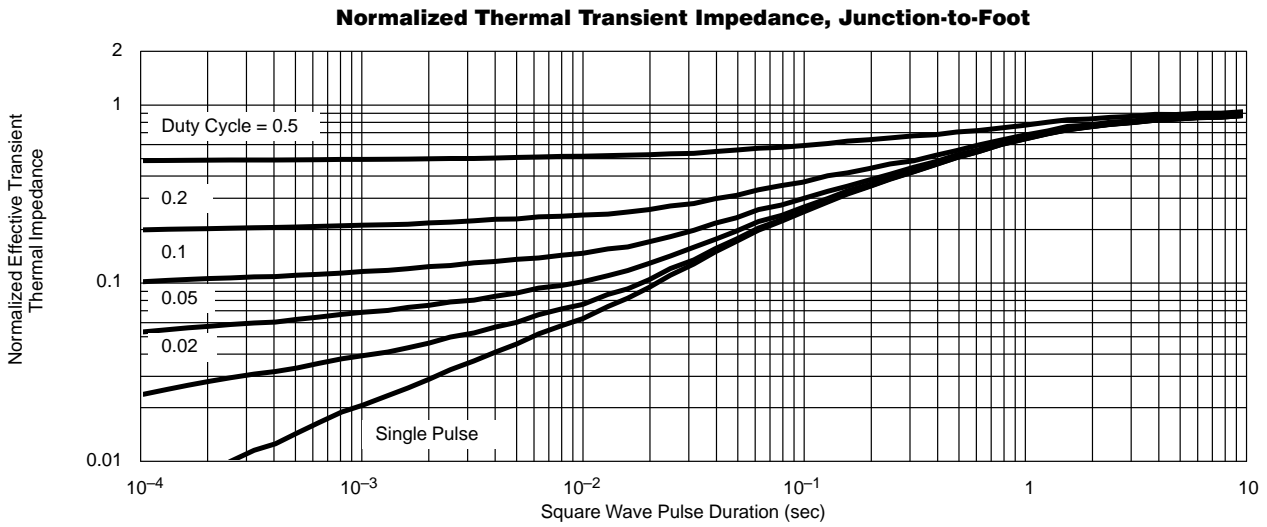


Normalized Thermal Transient Impedance, Junction-to-Ambient





TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)





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